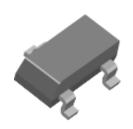
## N-Channel 60V (D-S) MOSFET

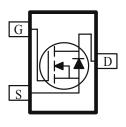
These miniature surface mount MOSFETs utilize High Cell Density process. Low  $r_{DS(on)}$  assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are power switch, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low r <sub>DS(on)</sub> Provides Higher Efficiency and
	Extends Battery Life

- Low Gate Charge
- Fast Switch
- Miniature SOT-23 Surface Mount Package Saves Board Space

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$r_{DS(on)}(\Omega)$	$I_{D}(A)$		
60	$0.194 @ V_{GS} = 10 V$	2.2		
00	$0.273 @ V_{GS} = 4.5V$	1.8		





ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)						
Parameter			Maximum	Units		
Drain-Source Voltage			60	V		
Gate-Source Voltage			±20	V		
C . D . C . A	$T_A=25^{\circ}C$	] ]T_	2.2			
Continuous Drain Current <sup>a</sup>	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	1.7	A		
Pulsed Drain Current <sup>b</sup>		$I_{DM}$	±15			
Continuous Source Current (Diode Conduction) <sup>a</sup>		$I_S$	1.7	A		
D D: : ,: a	$T_A=25^{\circ}C$	D	1.3	W		
Power Dissipation <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	LD	0.8	vv		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C		

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Maximum	Units			
M · I	t <= 5 sec	$R_{THJA}$	100	°C/W			
Maximum Junction-to-Ambient <sup>a</sup>	Steady-State		166				

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## Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Parameter	G	T C	Limits			TT . *4	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	VGS(th)	$V_{\rm DS} = V_{\rm GS},  I_{\rm D} = 250  \mathrm{uA}$	1.0			V	
Gate-Body Leakage	Igss	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zaro Cata Voltaga Drain Current	I <sub>DSS</sub>	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}$			1	η, Δ	
Zero Gate Voltage Drain Current		$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			50	uA	
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	10			Α	
D : G D : A	r <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 2.2 \text{ A}$			194		
Drain-Source On-Resistance <sup>A</sup>		$V_{GS} = 4.5 \text{ V}, I_D = 1.8 \text{ A}$			273	mΩ	
Forward Tranconductance <sup>A</sup>	gs	$V_{DS} = 4.5 \text{ V}, I_D = 2.2 \text{ A}$		8		S	
Diode Forward Voltage	$V_{\mathrm{SD}}$	$I_S = 1.7 A, V_{GS} = 0 V$			1.2	V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg			4.0			
Gate-Source Charge	Qgs	$V_{DS} = 30 \text{ V}, V_{GS} = 5 \text{ V}, I_{D} = 2.2 \text{ A}$		4.0		пC	
Gate-Drain Charge	Qgd			2.0			
Turn-On Delay Time	t <sub>d(on)</sub>			10			
Rise Time	tr	$V_{DD} = 30 \text{ V},  R_L = 30 \Omega,  I_D = 1 \text{ A},$		10			
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GEN} = 10 \text{ V}$		20		ns	
Fall-Time	$t_{\mathrm{f}}$			10			
Source-Ddrain Reverse Recovery Time	$t_{rr}$	$I_F = 1.7 \text{ A}, di/dt = 100 \text{ A/uS}$		50			

## Notes

- a. Pulse test:  $PW \le 300us duty cycle \le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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## Package Information

